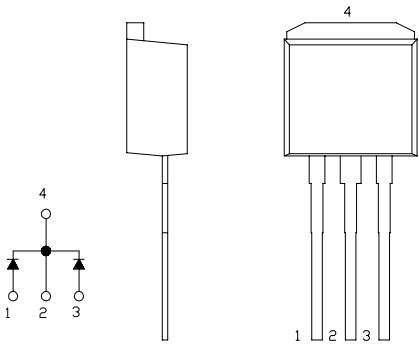


FRD Type : **C10T60F-11A**

OUTLINE DRAWING

FEATURES

- * Tabless TO-220
- * Dual Diodes – Cathode Common
- * Ultra – Fast Recovery
- * Low Forward Voltage Drop
- * High Surge Capability
- * 200 Volts thru 600 Volts Types Available



Maximum Ratings

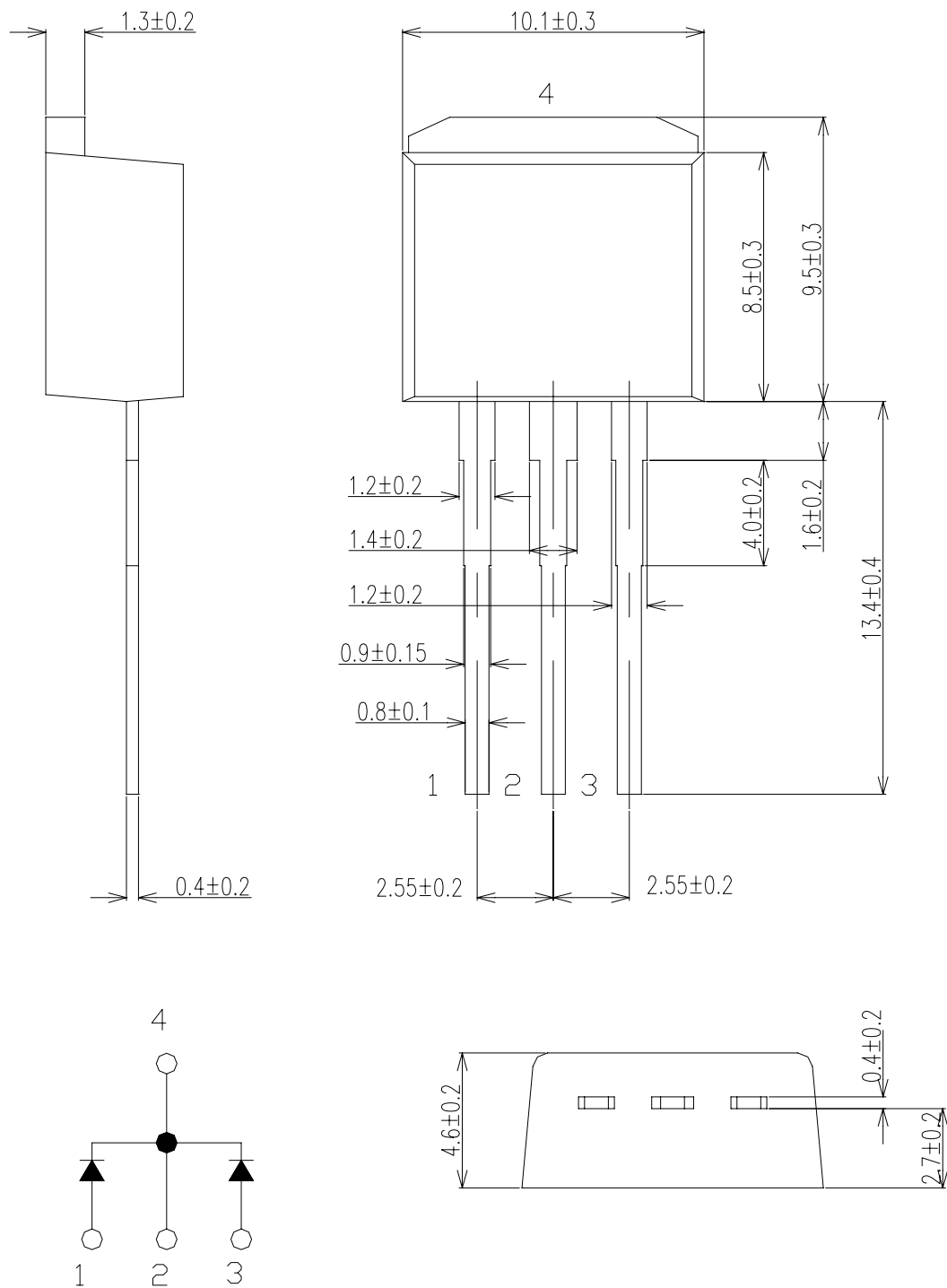
Approx Net Weight:1.75g

Rating	Symbol	C10T60F-11A			Unit
Repetitive Peak Reverse Voltage	V _{RRM}	600			V
Average Rectified Output Current	I _O	10	Tc=99℃	50 Hz,Full Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	11.1			A
Surge Forward Current	I _{FSM}	80	50 Hz Full Sine Wave,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T _{jw}	- 40 to + 150			℃
Storage Temperature Range	T _{stg}	- 40 to + 150			℃

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j=25^{\circ}\text{C}, V_{RM}=V_{RRM}$ per Arm	-	-	30	μA
Peak Forward Voltage	V_{FM}	$T_j=25^{\circ}\text{C}, I_{FM}=5\text{A}$ per Arm	-	-	1.7	V
Reverse Recovery Time	t_{rr}	$I_{FM}= 5\text{ A},$ $-di/dt= 50\text{ A}/\mu\text{s}, T_a= 25^{\circ}\text{C}$	-	-	40	ns
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	3	$^{\circ}\text{C}/\text{W}$

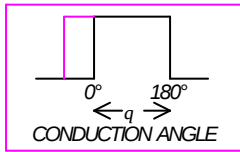
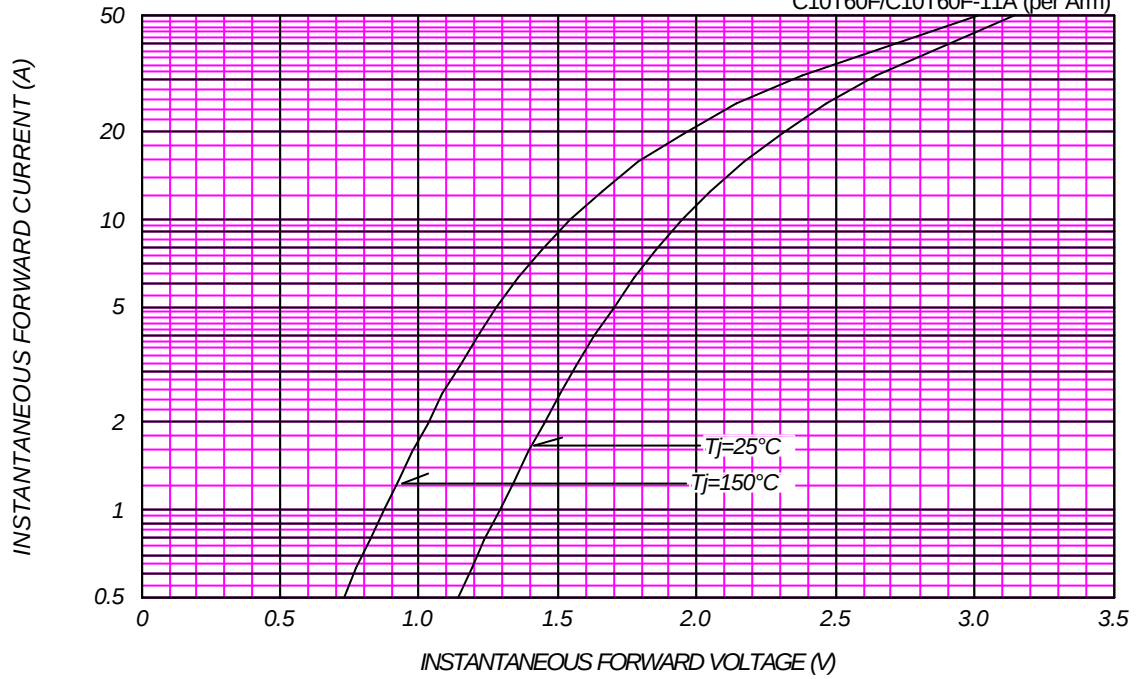
C_T_ 11A OUTLINE DRAWING (Dimensions in mm)



FORWARD CURRENT VS. VOLTAGE

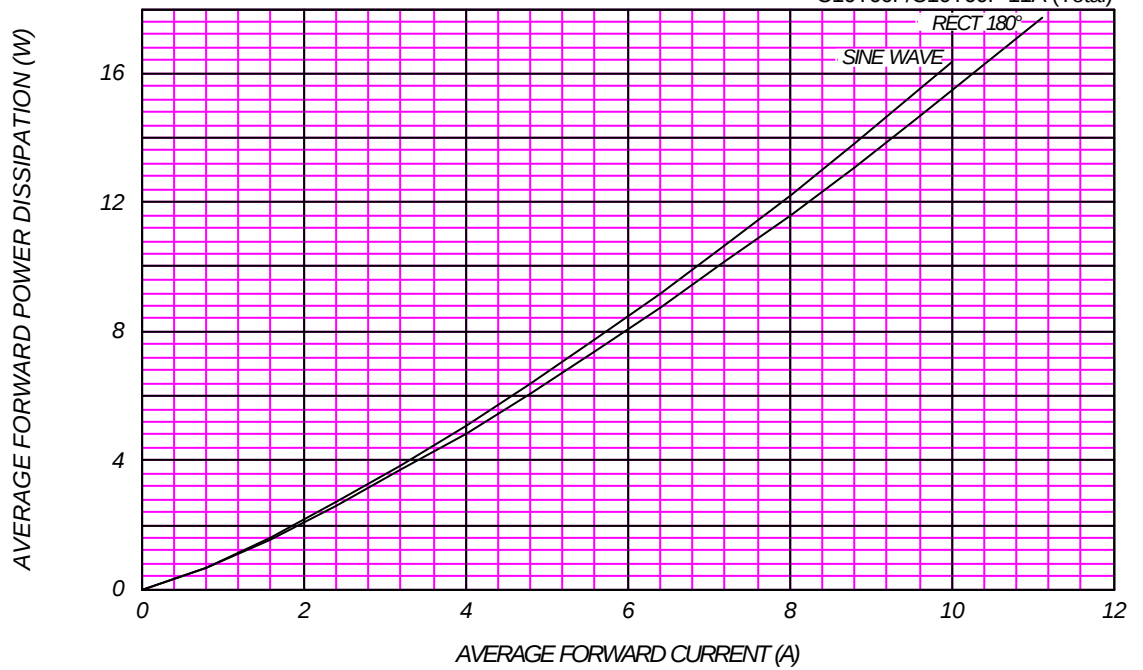
10ms Sine Wave Single Pulse

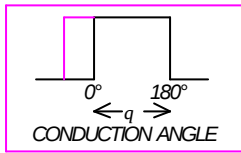
C10T60F/C10T60F-11A (per Arm)



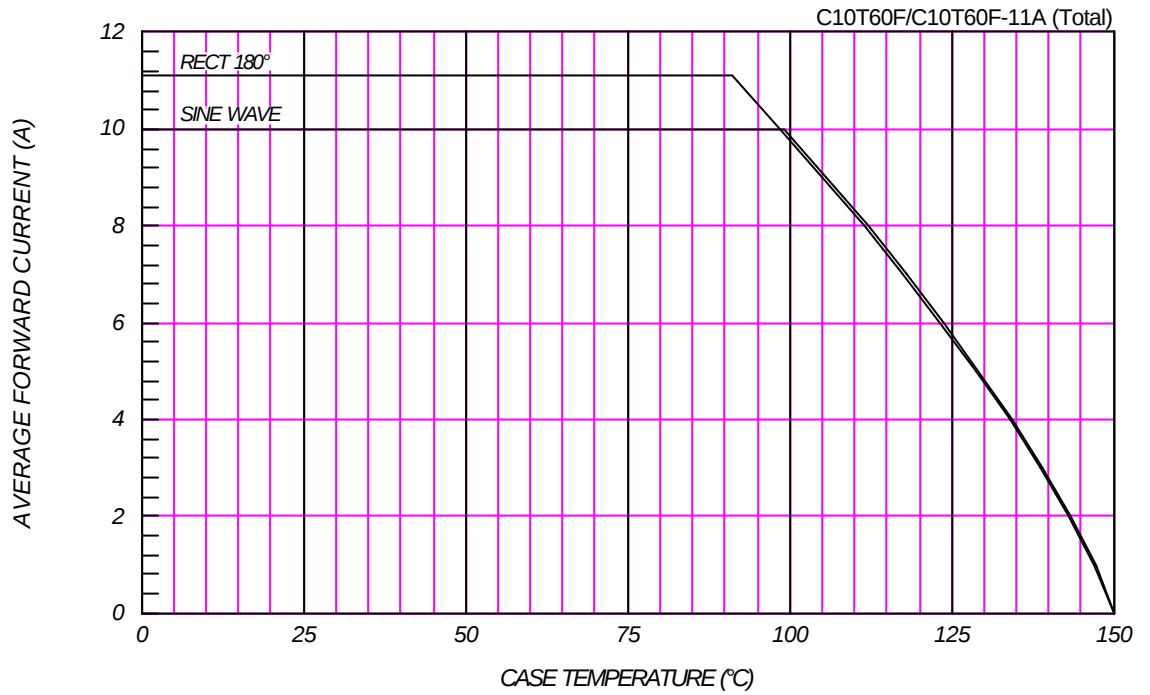
AVERAGE FORWARD POWER DISSIPATION

C10T60F/C10T60F-11A (Total)





AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE



SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load

